## SWITCHING N-CHANNEL POWER MOS FET

## Description

The 2SK2415 is N-Channel MOS Field Effect Transistor designed for high voltage switching applications.

## Features

- Low on-state resistance
$\operatorname{Rds}(o n) 1=0.10 \Omega \mathrm{MAX} .(\mathrm{VGS}=10 \mathrm{~V}, \mathrm{ID}=4.0 \mathrm{~A})$
$\operatorname{RdS}(o n)^{2}=0.15 \Omega \mathrm{MAX} .(\mathrm{VGS}=4 \mathrm{~V}, \mathrm{Id}=4.0 \mathrm{~A})$
- Low Ciss: Ciss $=570$ pF TYP.


## QUALITY GRADE

Standard
Please refer to "Quality Grades On NEC Semiconductor Devices" (Document number: C11531E) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applica5tions.


TO-252 (MP-3Z)


EQUIVALENT CIRCUIT


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$\star$ ELECTRICAL CHARACTERISTICS (TA $=25^{\circ} \mathrm{C}$ )

| CHARACTERISTIC | SYMBOL | MIN. | TYP. | MAX. | UNIT | TEST CONDITIONS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Drain to Source On-state Resistance | Ros(on)1 |  | 0.07 | 0.10 | $\Omega$ | V GS $=10 \mathrm{~V}, \mathrm{ID}=4.0 \mathrm{~A}$ |
|  | Ros(on)2 |  | 0.10 | 0.15 | $\Omega$ | $\mathrm{V}_{\mathrm{GS}}=4 \mathrm{~V}, \mathrm{ld}=4.0 \mathrm{~A}$ |
| Gate Cut-off Voltage | VGs(off) | 1.0 | 1.6 | 2.0 | V | $\mathrm{V} \mathrm{DS}=10 \mathrm{~V}, \mathrm{ID}=1 \mathrm{~mA}$ |
| Forward Transfer Admittance | $\mid \mathrm{yfs}$ \| | 5.0 | 8.4 |  | S | $\mathrm{V} \mathrm{DS}=10 \mathrm{~V}, \mathrm{ID}=4.0 \mathrm{~A}$ |
| Zero Gate Voltage Drain Current | Idss |  |  | 10 | $\mu \mathrm{A}$ | V ds $=60 \mathrm{~V}, \mathrm{~V}$ Gs $=0 \mathrm{~V}$ |
| Gate Leakage Current | Igss |  |  | $\pm 10$ | $\mu \mathrm{A}$ | $\mathrm{VGS}= \pm 20 \mathrm{~V}, \mathrm{~V}$ ds $=0 \mathrm{~V}$ |
| Input Capacitance | Ciss |  | 570 |  | pF | $\begin{aligned} & V_{D S}=10 \mathrm{~V} \\ & V_{G S}=0 \mathrm{~V} \\ & \mathrm{f}=1 \mathrm{MHz} \end{aligned}$ |
| Output Capacitance | Coss |  | 290 |  | pF |  |
| Reverse Transfer Capacitance | Crss |  | 75 |  | pF |  |
| Turn-On Delay Time | td(on) |  | 5 |  | ns | $\begin{aligned} & \mathrm{ld}=4.0 \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{GS}}=10 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}=30 \mathrm{~V} \\ & \mathrm{R}_{\mathrm{G}}=10 \Omega \end{aligned}$ |
| Rise Time | tr |  | 60 |  | ns |  |
| Turn-Off Delay Time | td(off) |  | 75 |  | ns |  |
| Fall Time | $\mathrm{t}_{\mathrm{f}}$ |  | 40 |  | ns |  |
| Total Gate Charge | QG |  | 21 |  | nC | $\begin{aligned} & \mathrm{ID}=8.0 \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{DD}}=48 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{GS}}=10 \mathrm{~V} \end{aligned}$ |
| Gate to Source Charge | Qgs |  | 2.0 |  | nC |  |
| Gate to Drain Charge | Qgd |  | 6.5 |  | nC |  |
| Body Diode Forward Voltage | $\mathrm{V}_{\text {F(S-D) }}$ |  | 1.0 |  | V | $\mathrm{I}_{\mathrm{F}}=8.0 \mathrm{~A}, \mathrm{~V}_{\mathrm{Gs}}=0 \mathrm{~V}$ |
| Reverse Recovery Time | trr |  | 85 |  | ns | $\begin{aligned} & \mathrm{I}_{\mathrm{F}}=8.0 \mathrm{~A}, \mathrm{~V}_{\mathrm{GS}}=0 \mathrm{~V} \\ & \mathrm{di} / \mathrm{dt}=100 \mathrm{~A} / \mu \mathrm{s} \end{aligned}$ |
| Reverse Recovery Charge | Qrr |  | 200 |  | nC |  |

* TEST CIRCUIT 1 AVALANCHE CAPABILITY

TEST CIRCUIT 2 SWITCHING TIME


## TEST CIRCUIT 3 GATE CHARGE



The application circuits and their parameters are for references only and are not intended for use in actual design-in's.

TYPICAL CHARACTERISTICS ( $\mathrm{TA}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ )




DRAIN CURRENT vs. drain to source voltage


TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH




DRAIN TO SOURCE ON-STATE
RESITANCE vs. DRAIN CURRENT


GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE




REVERSE RECOVERY TIME vs. DRAIN CURRENT



Vsd - Source to Drain Voltage - V


DYNAMIC INPUT/OUTPUT CHARACTERISTICS



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